

## 1. General description

AC Thyristor power switch in a SOT54 plastic package with self-protective capabilities against low and high energy transients

## 2. Features and benefits

- Exclusive negative gate triggering
- Full cycle AC conduction
- Remote gate separates the gate driver from the effects of the load current
- Very high noise immunity
- Safe clamping of low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients

## 3. Applications

- Fan motor circuits
- Pump motor circuits
- Lower-power highly inductive, resistive and safety loads

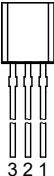
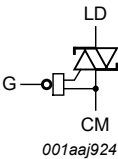
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	-	600	V
$I_{\text{T(RMS)}}$	RMS on-state current	full sine wave; $T_{\text{lead}} \leq 71\text{ °C}$ ; <a href="#">Fig. 1</a>	-	-	0.8	A
<b>Static characteristics</b>						
$I_{\text{GT}}$	gate trigger current	$V_{\text{D}} = 12\text{ V}$ ; $I_{\text{T}} = 100\text{ mA}$ ; LD+ G-; $T_{\text{j}} = 25\text{ °C}$ ; <a href="#">Fig. 6</a>	1	-	10	mA
		$V_{\text{D}} = 12\text{ V}$ ; $I_{\text{T}} = 100\text{ mA}$ ; LD- G-; $T_{\text{j}} = 25\text{ °C}$ ; <a href="#">Fig. 6</a>	1	-	10	mA

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	CM	common	 TO-92 (SOT54)	 001aaJ924
2	G	gate		
3	LD	load		

6. Ordering information

Table 3. Ordering information

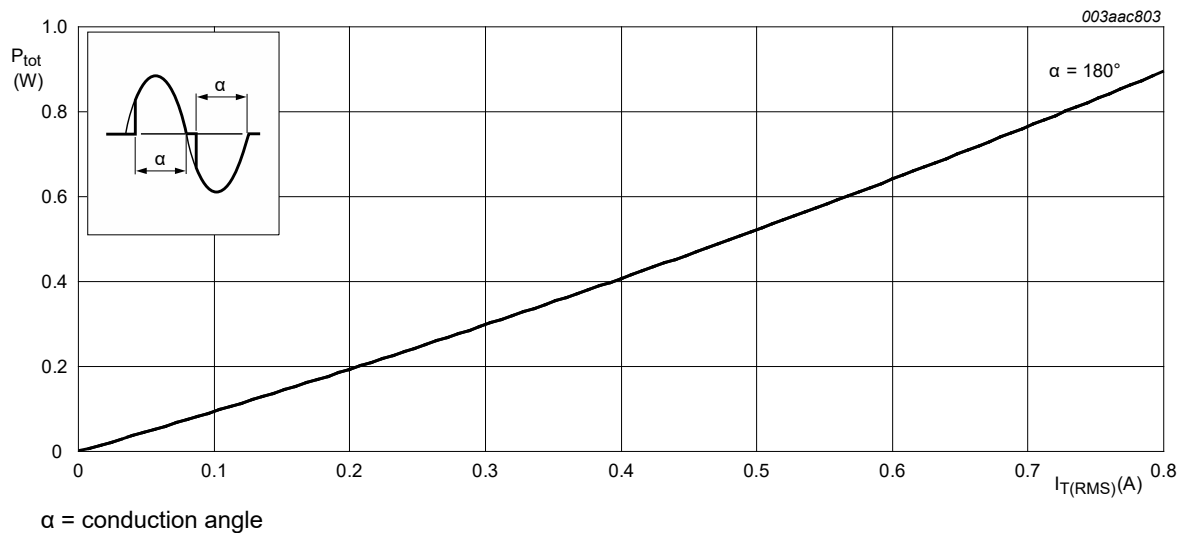
Type number	Package		
	Name	Description	Version
ACT108-600E	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

## 7. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	600	V
$I_{\text{T(RMS)}}$	RMS on-state current	full sine wave; $T_{\text{lead}} \leq 71\text{ }^{\circ}\text{C}$ ; <a href="#">Fig. 1</a>	-	0.8	A
$I_{\text{TSM}}$	non-repetitive peak on-state current	full sine wave; $T_{\text{j(init)}} = 25\text{ }^{\circ}\text{C}$ ; $t_{\text{p}} = 20\text{ ms}$ ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 3</a>	-	13	A
		full sine wave; $T_{\text{j(init)}} = 25\text{ }^{\circ}\text{C}$ ; $t_{\text{p}} = 16.7\text{ ms}$	-	14.3	A
$I^2t$	$I^2t$ for fusing	$t_{\text{p}} = 10\text{ ms}$ ; SIN	-	0.32	$\text{A}^2\text{s}$
$di_{\text{T}}/dt$	rate of rise of on-state current	$I_{\text{G}} = 20\text{ mA}$	-	100	$\text{A}/\mu\text{s}$
$I_{\text{GM}}$	peak gate current	$t = 20\text{ }\mu\text{s}$	-	1	A
$V_{\text{GM}}$	peak gate voltage	positive applied gate voltage	-	15	V
$P_{\text{G(AV)}}$	average gate power	over any 20 ms period	-	0.1	W
$T_{\text{stg}}$	storage temperature		-40	150	$^{\circ}\text{C}$
$T_{\text{j}}$	junction temperature		-	125	$^{\circ}\text{C}$
$V_{\text{PP}}$	peak pulse voltage	$T_{\text{j}} = 25\text{ }^{\circ}\text{C}$ ; non-repetitive, off-state; ten pulses on each voltage polarity; 20s or more between successive pulses;; <a href="#">Fig. 4</a>	-	2.5	kV



**Fig. 1. Total power dissipation as a function of RMS on-state current; maximum values**

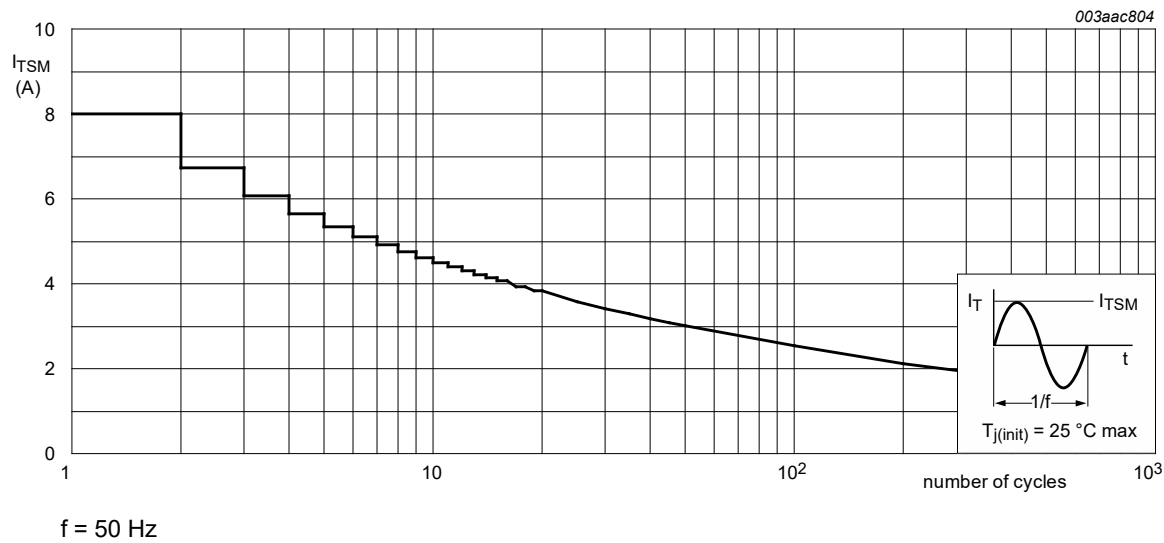


Fig. 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

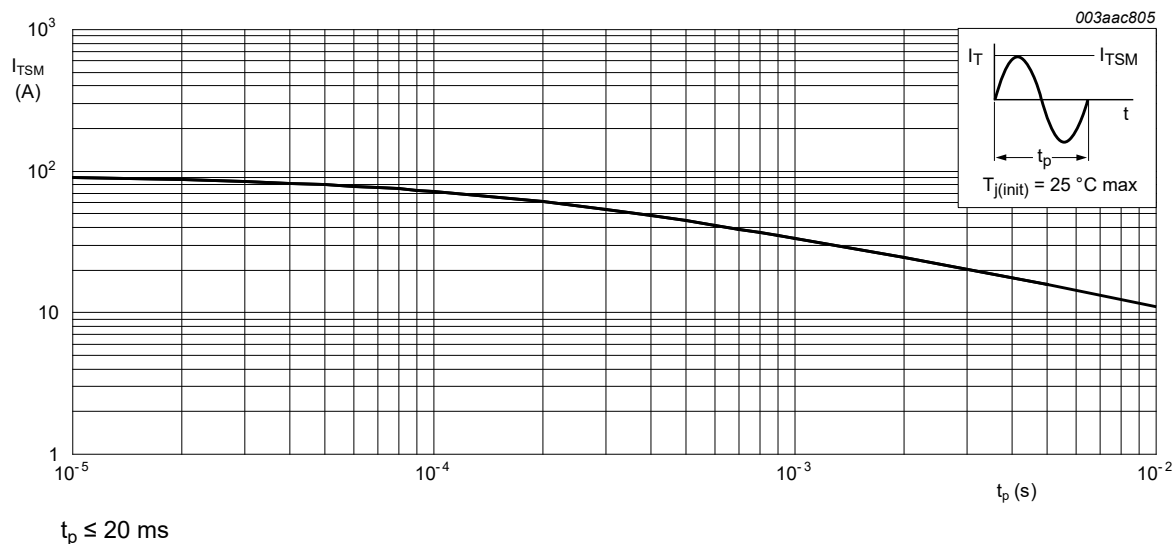


Fig. 3. Non-repetitive peak on-state current as a function of pulse width; maximum values

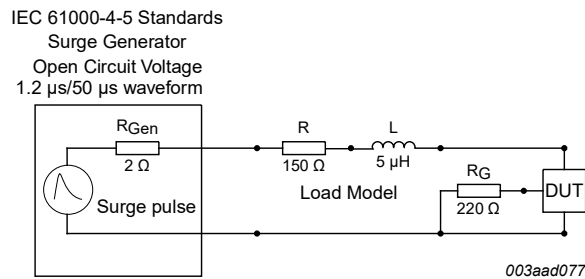
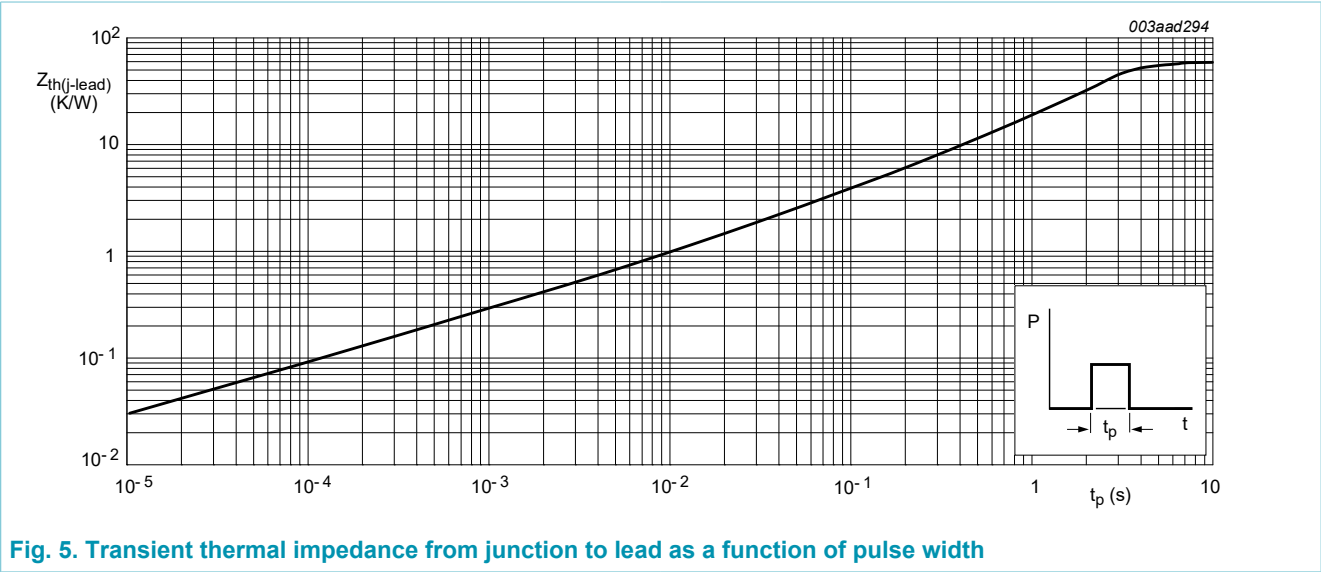


Fig. 4. Test circuit for inductive and resistive loads with conditions equivalent to IEC 61000-4-5

8. Thermal characteristics

Table 5. Thermal characteristics

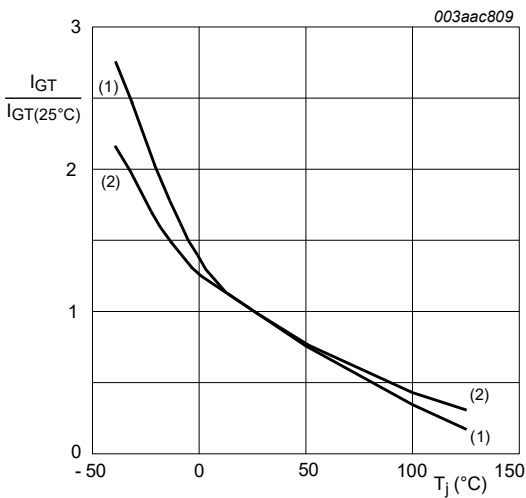
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle with heatsink compound; <a href="#">Fig. 5</a>	-	-	60	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	full cycle; printed-circuit board mounted; lead length 4 mm	-	150	-	K/W



## 9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Static characteristics</b>							
$I_{GT}$	gate trigger current	$V_D = 12\text{ V}$ ; $I_T = 100\text{ mA}$ ; LD+ G-; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 6</a>		1	-	10	mA
		$V_D = 12\text{ V}$ ; $I_T = 100\text{ mA}$ ; LD- G-; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 6</a>		1	-	10	mA
$I_L$	latching current	$V_D = 12\text{ V}$ ; $I_G = 100\text{ mA}$ ; LD+ G-; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 7</a>		-	-	25	mA
		$V_D = 12\text{ V}$ ; $I_G = 100\text{ mA}$ ; LD- G-; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 7</a>		-	-	20	mA
$I_H$	holding current	$V_D = 12\text{ V}$ ; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 7</a>		-	-	20	mA
$V_T$	on-state voltage	$I_T = 1.1\text{ A}$ ; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 8</a>		-	-	1.3	V
$V_{GT}$	gate trigger voltage	$V_D = 400\text{ V}$ ; $I_T = 100\text{ mA}$ ; $T_j = 125\text{ }^\circ\text{C}$		0.15	-	-	V
		$V_D = 12\text{ V}$ ; $I_T = 100\text{ mA}$ ; $T_j = 25\text{ }^\circ\text{C}$		-	-	1	V
$I_D$	off-state current	$V_D = 600\text{ V}$ ; $T_j = 25\text{ }^\circ\text{C}$		-	-	2	$\mu\text{A}$
		$V_D = 600\text{ V}$ ; $T_j = 125\text{ }^\circ\text{C}$		-	-	0.2	mA
$V_{CL}$	clamping voltage	$I_{CL} = 0.1\text{ mA}$ ; $t_p = 1\text{ ms}$ ; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 9</a>		650	-	-	V
<b>Dynamic characteristics</b>							
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM} = 402\text{ V}$ ; $T_j = 125\text{ }^\circ\text{C}$ ; ( $V_{DM} = 67\%$ of $V_{DRM}$ ); exponential waveform; gate open circuit; <a href="#">Fig. 10</a>		2000	-	-	V/ $\mu\text{s}$
$dI_{com}/dt$	rate of change of commutating current	$V_D = 400\text{ V}$ ; $T_j = 125\text{ }^\circ\text{C}$ ; $I_{T(RMS)} = 0.8\text{ A}$ ; $dV_{com}/dt = 20\text{ V}/\mu\text{s}$ ; (snubberless condition); gate open circuit; <a href="#">Fig. 11</a> ; <a href="#">Fig. 12</a>		0.5	-	-	A/ms



(1) LD+ G-  
(2) LD- G-

Fig. 6. Normalized gate trigger current as a function of junction temperature

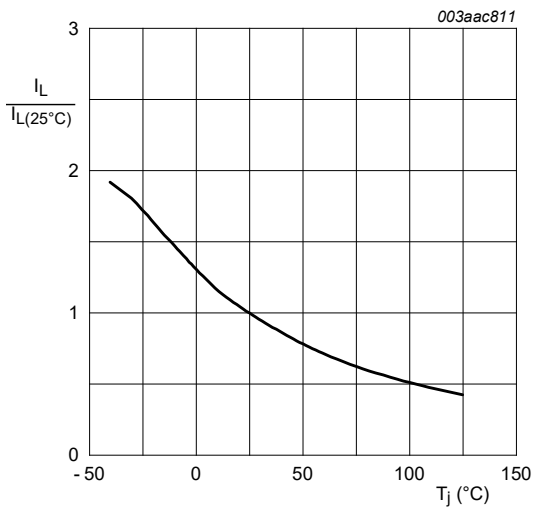
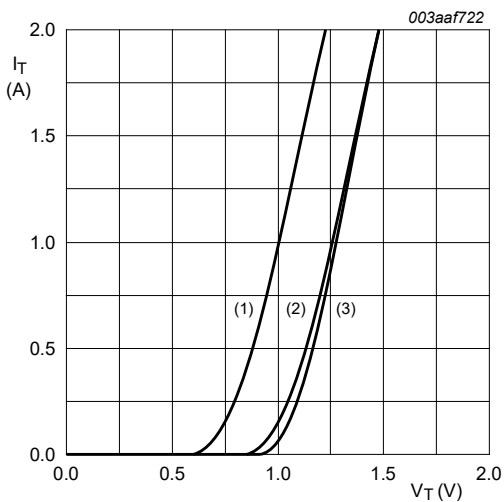


Fig. 7. Normalized latching current as a function of junction temperature



$V_o = 0.758\text{ V}$ ;  $R_s = 0.263\text{ }\Omega$   
(1)  $T_j = 125^{\circ}\text{C}$ ; typical values  
(2)  $T_j = 125^{\circ}\text{C}$ ; maximum values  
(3)  $T_j = 25^{\circ}\text{C}$ ; maximum values

Fig. 8. On-state current as a function of on-state voltage

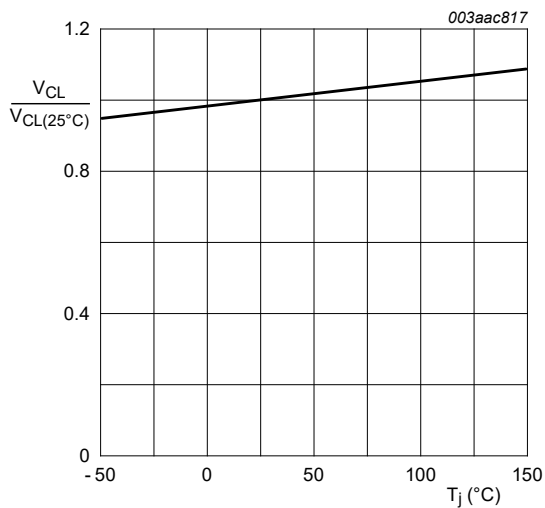


Fig. 9. Normalized clamping voltage (upper limit) as a function of junction temperature; minimum values

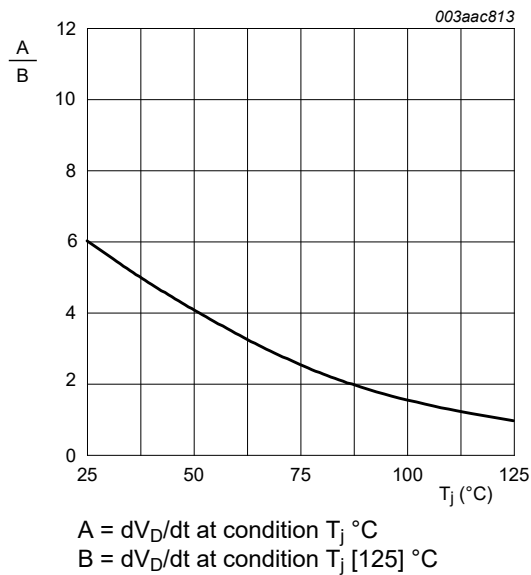


Fig. 10. Normalized rate of rise of off-state voltage as a function of junction temperature

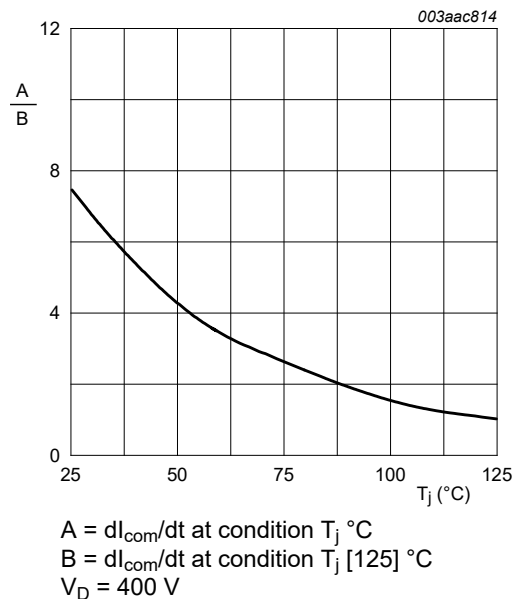
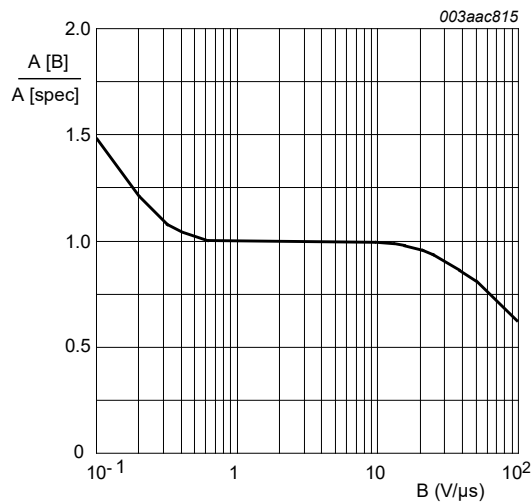


Fig. 11. Normalized critical rate of rise of commutating current as a function of junction temperature



$A [B] = dI_{com}/dt$  at condition  $B$ ,  $dV_{com}/dt$   
 $A [spec]$  is the data sheet value for  $dI_{com}/dt$   
turn-off time is less than 20 ms

Fig. 12. Normalized critical rate of change of commutating current as a function of critical rate of change of commutating voltage; minimum values



10. Package outline

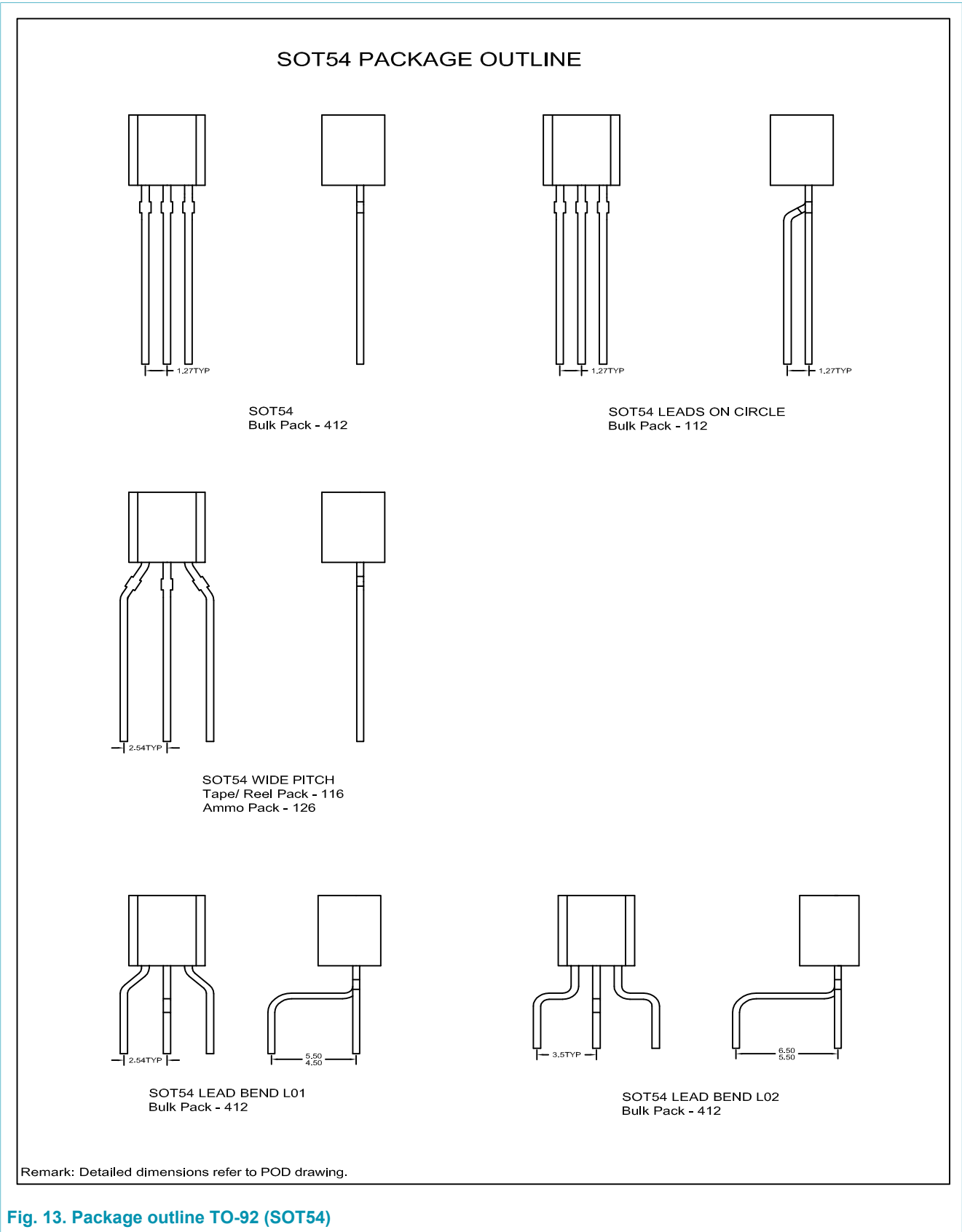


Fig. 13. Package outline TO-92 (SOT54)

## 11. Legal information

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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